

Thermal neutron induces Single-Event Upsets in the FPGA used in particle physics experiments

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Introduction

Radiation on Particle Physics Experiments

To explore beyond the Standard Model, beams generated by accelerators are becoming **higher intensity, higher luminosity and higher energy**.
→ **increase background radiations**

(neutron, gamma, proton, etc.)

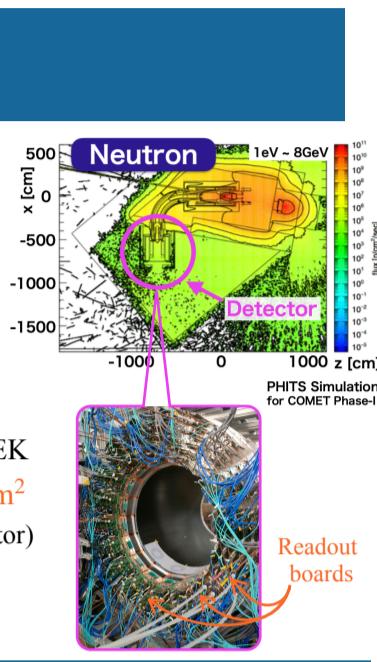
→ **affects electronics**.

e.g.) COMET ^[1] @ J-PARC, SuperKEKB/Belle II ^[2] @ KEK

Estimated cumulative neutron dose $\sim 10^{12} \text{ n}_{1-\text{MeV eq}}/\text{cm}^2$

(Including safety factor)

There is a large amount of **thermal neutrons** around the detector readout electronics.



Neutron effect

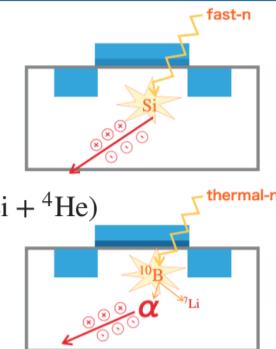
• Fast neutron ($> 0.1 \text{ MeV}$): nuclear reaction with Si
→ **emit Ion particle**

• Thermal neutron ($< 1 \text{ eV}$): capture reaction with ^{10}B
→ **emit α particle** ($^{10}\text{B} + \text{n} \rightarrow ^7\text{Li} + ^4\text{He}$)

→ Induce electron-hole pairs

→ **Change the logic state (Single-Event Upset, SEU)**

Counterplan: neutron shield, error-correcting code, etc.



Semiconductor design & SEU occurred by thermal neutron

Trend: ^{10}B less oxide film is used → SEUs by thermal neutron decreased...?

→ Some studies reported SEUs induced by thermal neutrons [3], [4].

It might still contain ^{10}B ? / SEU trends vary depending on the product type.

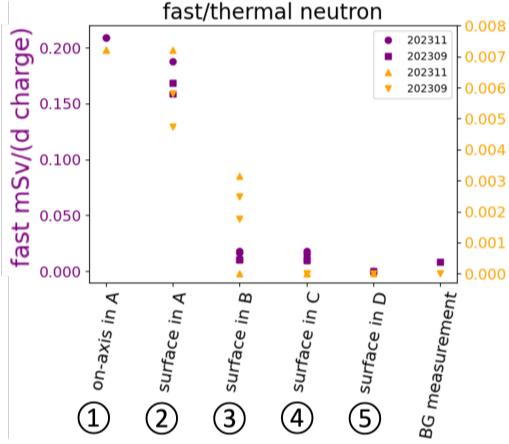
Motivation of this study

To estimate SEUs caused by thermal neutrons in an FPGA

(For fast neutrons, it has been studied in [5].)

Result & Discussion

Neutron measurement



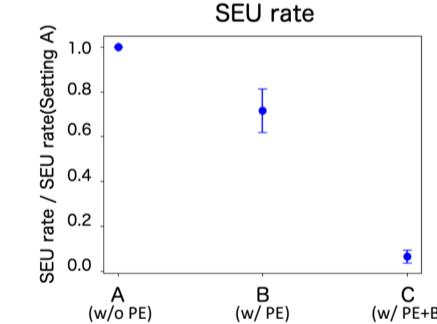
- Without blocks, both fast and thermal neutrons were irradiated. (1, 2)
- The one-minute measurement in 202309-thermal (▲) was too short to detect in (3).
- Thermal and fast neutrons are successfully shielded in (4) due to B_2O_3 -containing blocks.
- Most thermal neutrons came from the reflection of the behind block in (5) compare to (3).

→ Confirmed neutron energy trend
A : fast, thermal
B : thermal
C : neither fast nor thermal

SEU measurement

Setup	SEU count	deutron charge[C]	SEU / (d charge)
A	113	4.9×10^3	2.3×10^{-2}
B	104	6.2×10^3	1.7×10^{-2}
C	6	4.0×10^3	1.5×10^{-3}

SEU counts increased in proportion to the beam charge →



← The SEU rate on each setups relative to the result of A

★ It was found that SEUs occurred due to thermal neutrons.

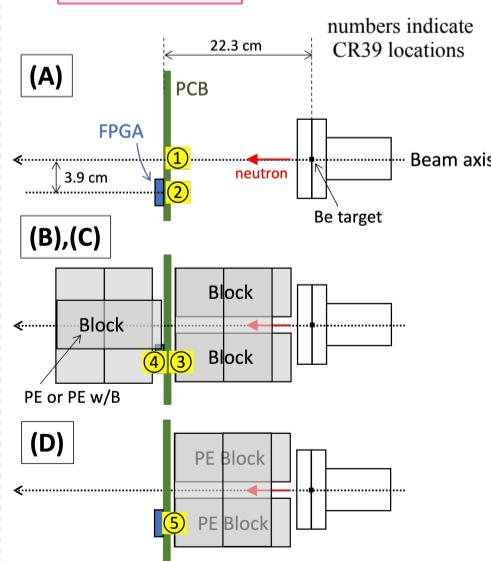
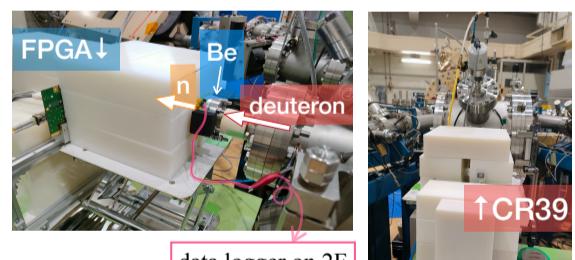
★ Shielding of B_2O_3 -containing blocks greatly contributes to reducing the SEUs.

Conclusion & Future

- Particle physics experiments using the beam of high-intensity, luminosity, and energy require consideration of radiation effects on electronics.
- Fast neutrons and thermal neutrons can induce charged particles inside transistors through different processes, which can cause SEUs.
- We investigated SEUs induced by thermal neutrons using an FPGA employed in a particle experiment.
- By placing polyethylene blocks, we succeeded in producing thermal neutrons from a tandem accelerator and observed SEUs caused by thermal neutrons.
- We showed that it is necessary to consider the influence of thermal neutrons in the experiments and the usefulness of countermeasures such as shielding.

Future work

- To better understand the rate of SEU
 - ★ Simulating a detailed neutron energy distribution
 - ★ Measuring the energy
- Investigate where and how much ^{10}B is contained by elemental analysis



(A) : Without blocks (reference)

CR39 - ① On-axis, ② FPGA surface

(B) : With Polyethylene (PE) blocks (degrade or reflect fast neutrons)

CR39 - ③ FPGA surface

(C) : With PE blocks containing B_2O_3 (shield both fast and thermal neutrons)

CR39 - ④ FPGA surface

(D) : Remove blocks behind FPGA from (B) (investigate the impact of behind block = reflected-derived thermal neutrons)

CR39 - ⑤ FPGA surface

Background (BG) CR39 - no irradiation

Acknowledgement

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